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# HA17558 Serise

Dual Operational Amplifier

# HITACHI

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## Description

HA17558 is dual operational amplifiers which provides internal frequency compensation and high performance. It can be applied widely to measuring control equipment and to general Use. The two amplifiers share a common bias network and power supply leads.

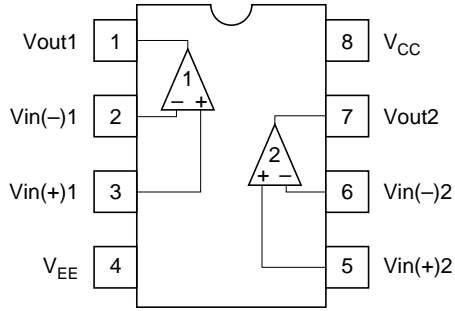
## Features

- High voltage Gain: 104dB (Typ)
- High speed: 1V/ $\mu$ s
- Continuous short-circuit protection
- Low-noise operational amplifiers
- Internal frequency compensation

## Ordering Information

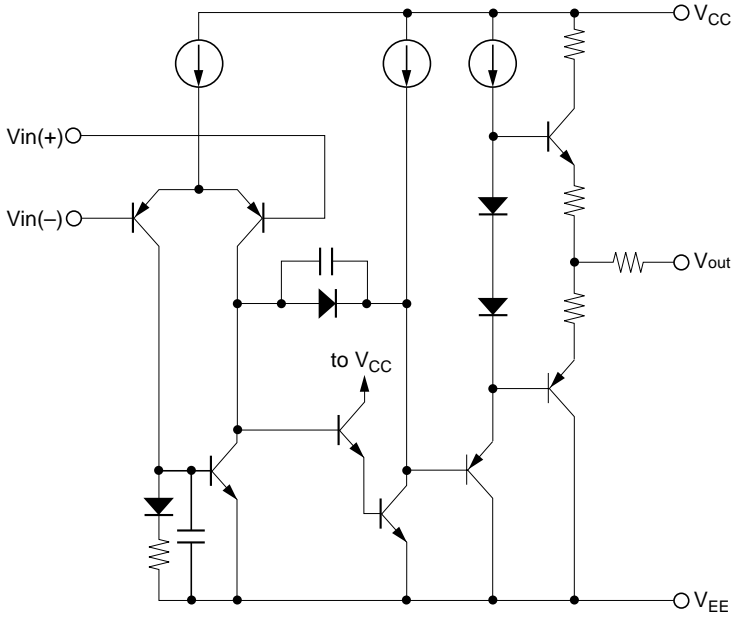
Type No.	Application	Package
HA17558FP	Industrial use	FP-8D
HA17558F	Commercial use	FP-8D
HA17558	Commercial use	DP-8
HA17558PS	Industrial use	DP-8

## Pin Arrangement



(Top View)

## Circuit Schematic (1/2)



**Absolute Maximum Ratings** (Ta = 25°C)

Item	Symbol	Ratings				Unit
		HA17558	HA17558 PS	HA17558 F	HA17558 FP	
Supply voltage	V <sub>CC</sub>	+18	+18	+18	+18	V
	V <sub>EE</sub>	-18	-18	-18	-18	V
Differential input voltage	V <sub>IN (diff)</sub>	±30	±30	±30	±30	V
Common-mode input voltage	V <sub>CM</sub> <sup>*3</sup>	±15	±15	±15	±15	V
Power dissipation	P <sub>T</sub>	670 <sup>*1</sup>	670 <sup>*1</sup>	385 <sup>*2</sup>	385 <sup>*2</sup>	mW
Operating temperature	Topr	-20 to +75	-20 to +75	-20 to +75	-20 to +75	-20 to +75
Storage temperature	Tstg	-55 to +125	-55 to +125	-55 to +125	-55 to +125	°C

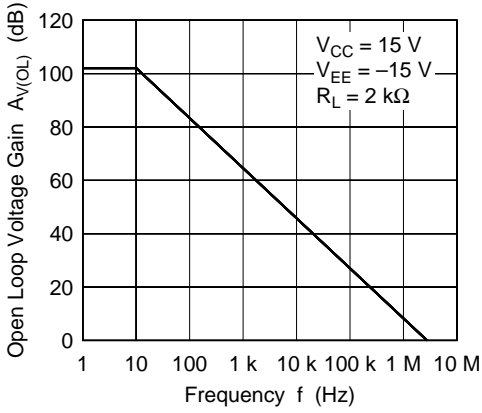
- Notes: 1. These are the allowable values up to Ta = 45 °C. Derate by 8.3mW/°C above that temperature.  
 2. These are the allowable values up to Ta = 31 °C mounting on 30% wiring density glass epoxy board. Derate by 7.14mW/°C above that temperature.  
 3. If the supply voltage is less than ±15V, input voltage should be less than supply voltage.

**Electrical Characteristics** (Ta = 25°C, V<sub>CC</sub> = +15V, V<sub>EE</sub> = -15V)

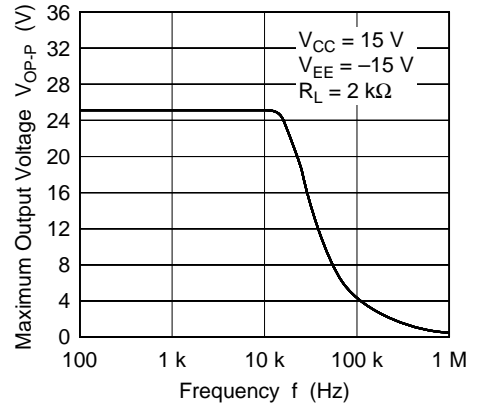
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Input offset voltage	V <sub>IO</sub>	—	0.5	6	mV	R <sub>s</sub> ≤ 10kΩ
Input offset current	I <sub>IO</sub>	—	5	200	nA	
Input bias current	I <sub>IB</sub>	—	50	500	nA	
Voltage gain	A <sub>VD</sub>	86	104	—	dB	R <sub>L</sub> ≥ 2kΩ, V <sub>O</sub> = ±10V
Maximum output voltage	V <sub>op-p</sub>	±12	±14	—	V	R <sub>L</sub> ≥ 10kΩ
Maximum output voltage	V <sub>op-p</sub>	±10	±12.4	—	V	R <sub>L</sub> ≥ 2kΩ
Common mode input voltage range	V <sub>CM</sub>	±12	±14	—	V	
Common mode rejection ratio	CMR	70	100	—	dB	R <sub>s</sub> ≤ 10kΩ
Supply voltage rejection ratio	PSRR	—	10	150	μV/V	R <sub>s</sub> ≤ 10kΩ
Power dissipation	Pd	—	90	170	mW	2-channel, No load
Slew rate	SR	—	1.0	—	V/μs	A <sub>VD</sub> = 1
Equivalent input noise voltage	V <sub>NI</sub>	—	6	—	μVp-p	R <sub>s</sub> = 1kΩ, f = 1Hz to 1kHz
Channel separation	CS	—	105	—	dB	f = 1kHz

## Characteristic Curves

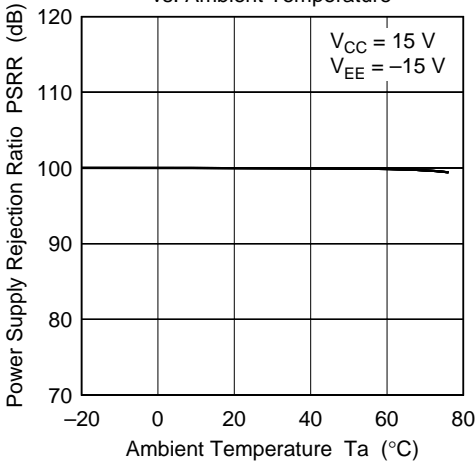
Open Loop Voltage Gain vs. Frequency



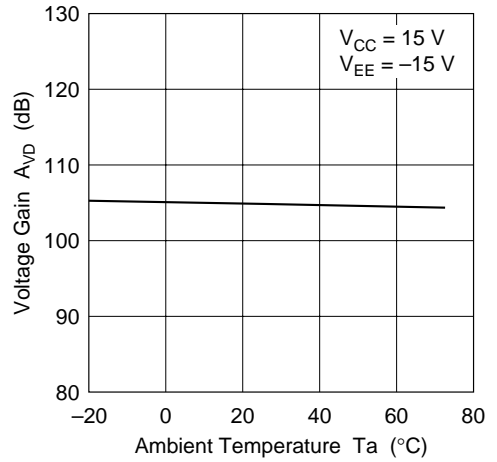
Maximum Output Voltage vs. Frequency



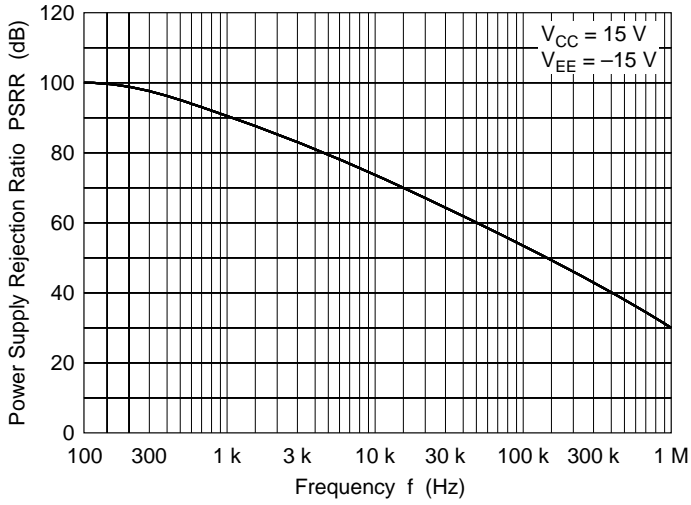
Power Supply Rejection Ratio vs. Ambient Temperature



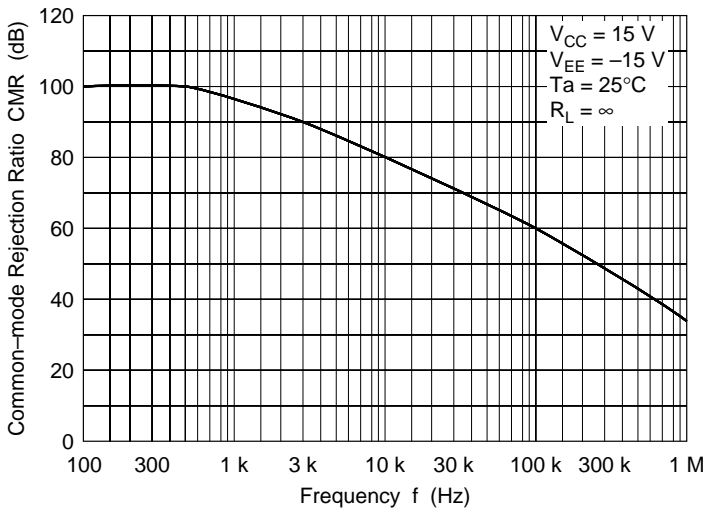
Voltage Gain vs. Ambient Temperature

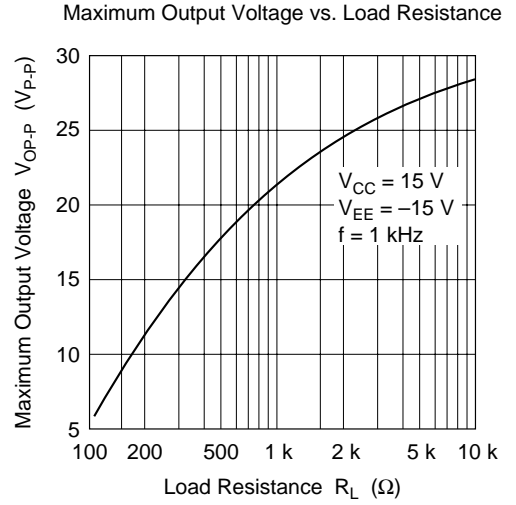
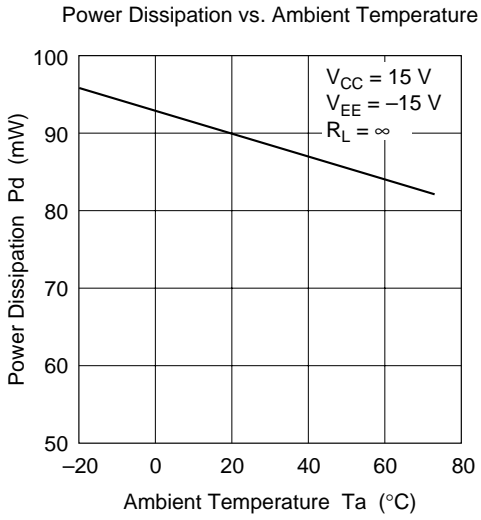
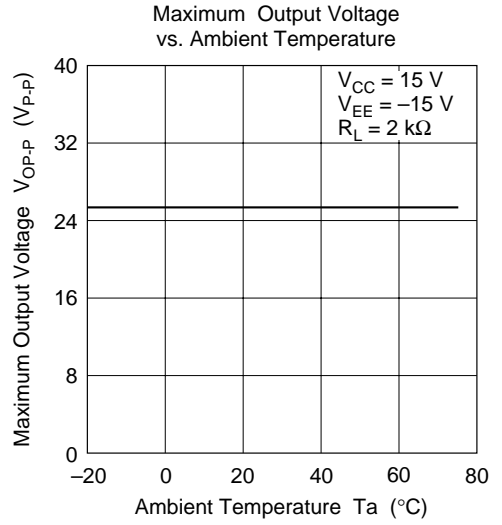
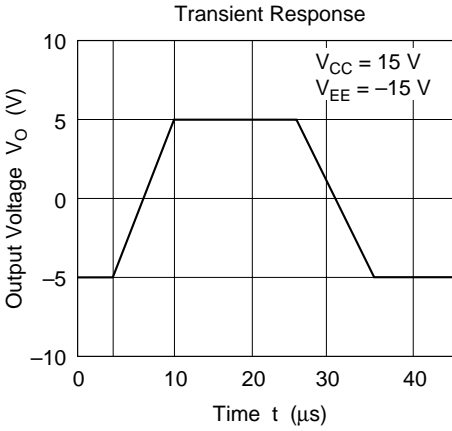


Power Supply Rejection Ratio vs. Frequency

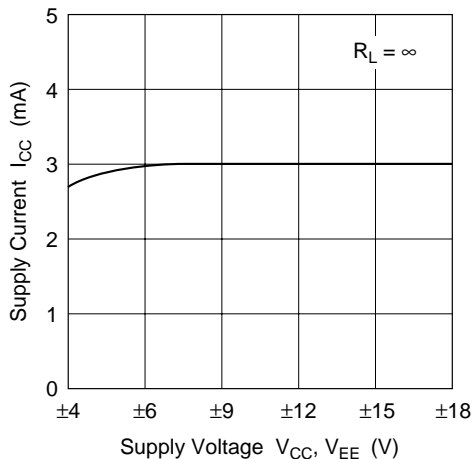


Common-mode Rejection Ratio vs. Frequency

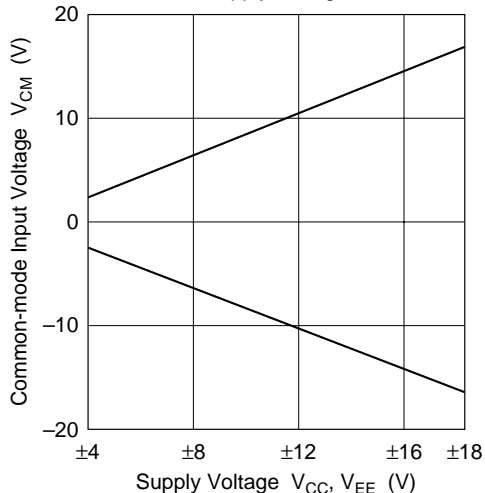




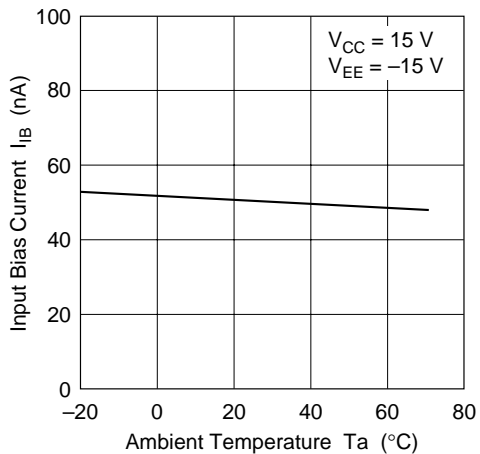
Supply Current vs. Supply Voltage



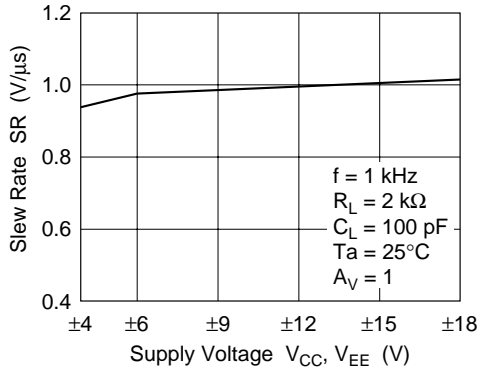
Common-mode Input Voltage vs. Supply Voltage



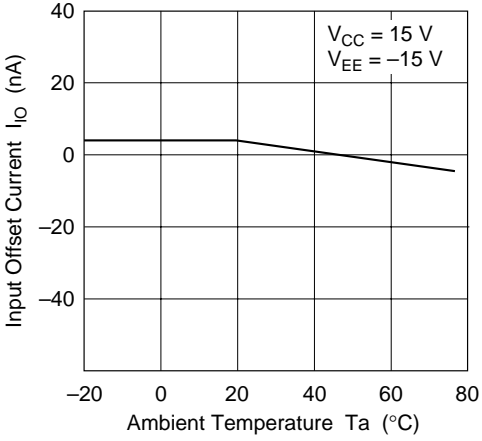
Input Bias Current vs. Ambient Temperature



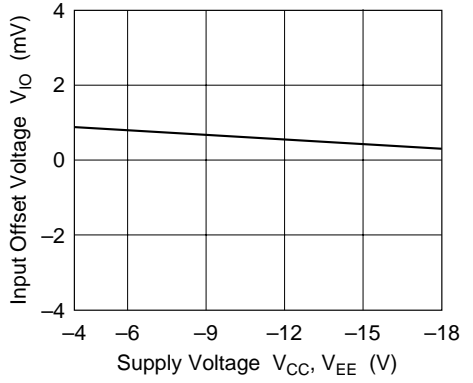
Slew Rate vs. Supply Voltage



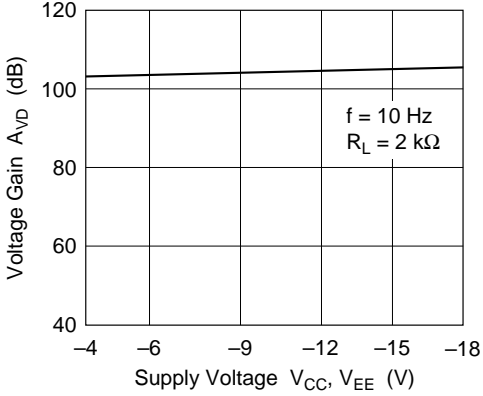
Input Offset Current vs. Ambient Temperature



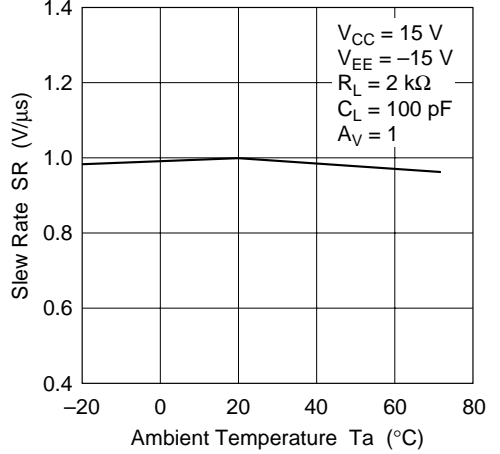
Input Offset Voltage vs. Supply Voltage



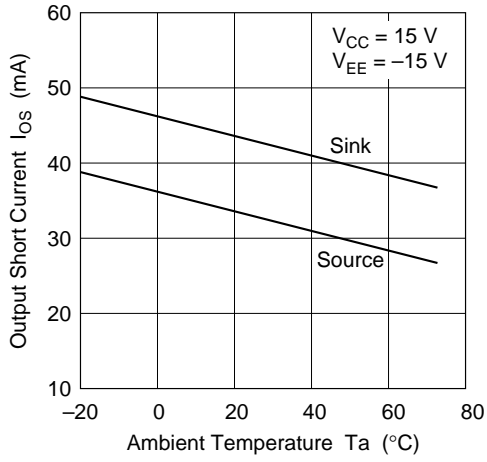
Voltage Gain vs. Supply Voltage



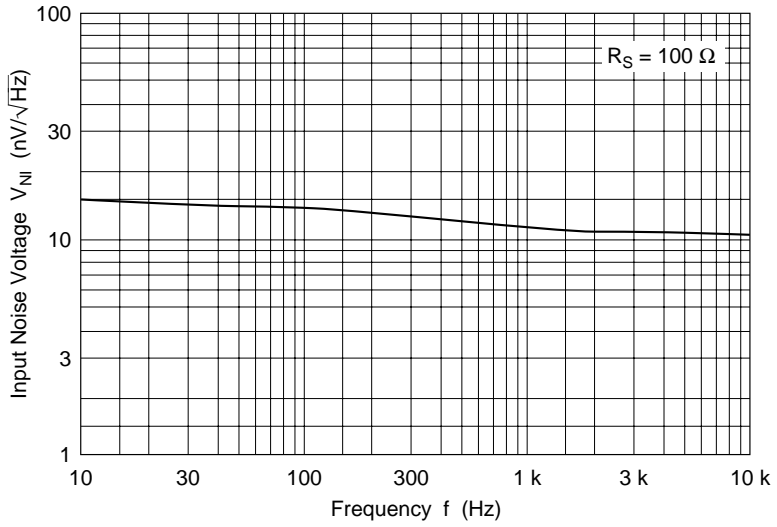
Slew Rate vs. Ambient Temperature



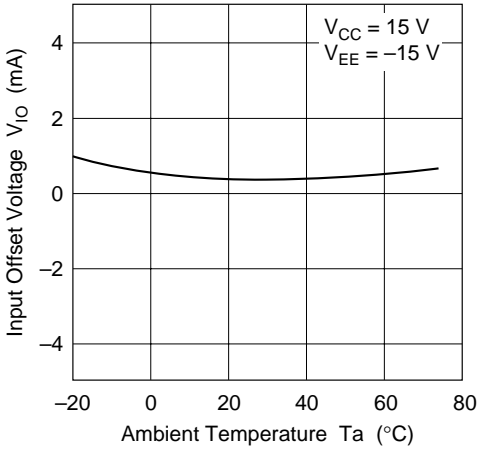
Output Short Current vs. Ambient Temperature



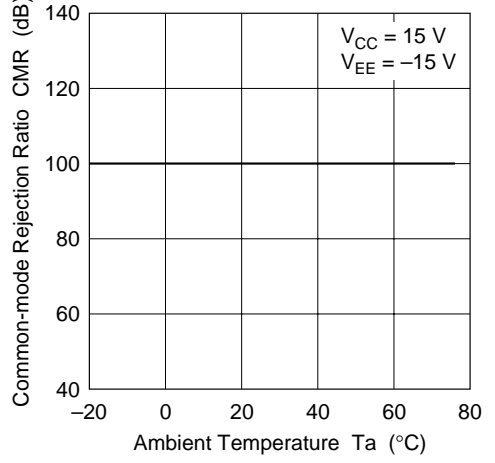
Input Noise Voltage vs. Frequency



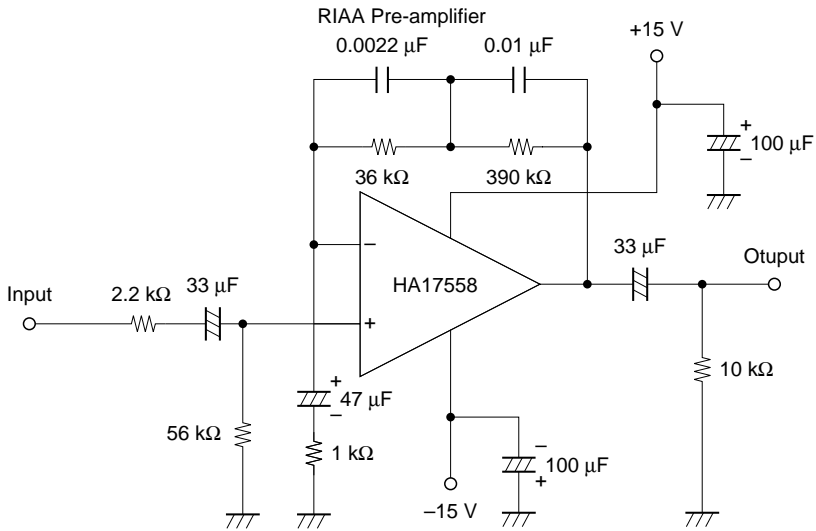
Input Offset Voltage vs. Ambient Temperature



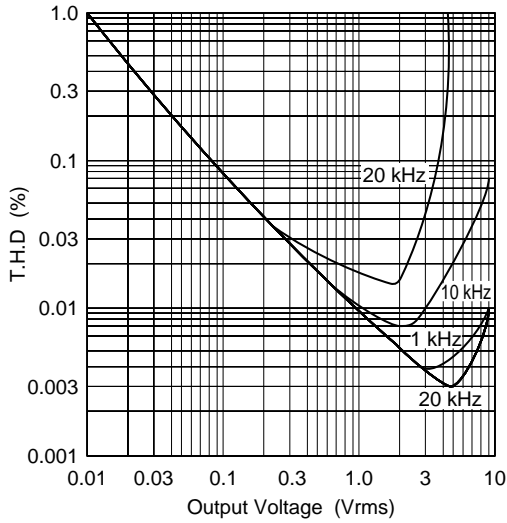
Common-mode Rejection Ratio vs. Ambient Temperature



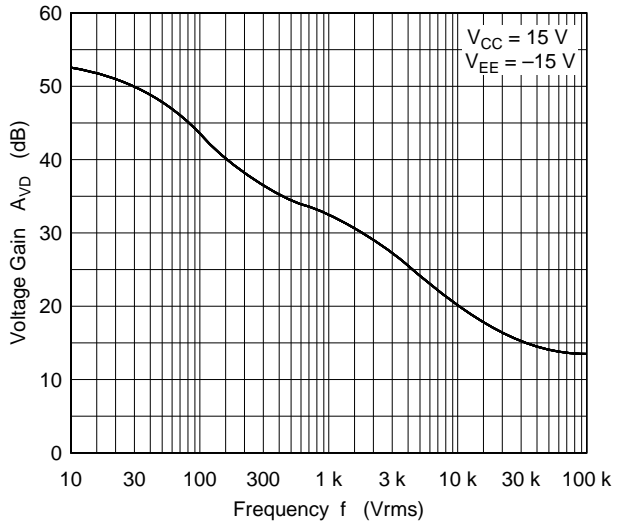
Circuit Example



T.H.D. vs. Output Voltage (RIAA Pre-Amp)

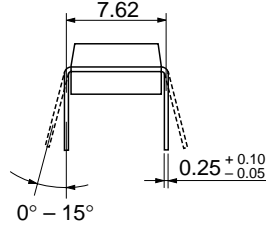
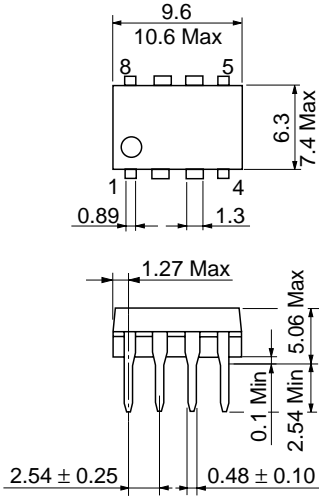


T.H.D. vs. Output Voltage (RIAA Pre-Amp)



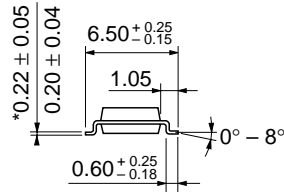
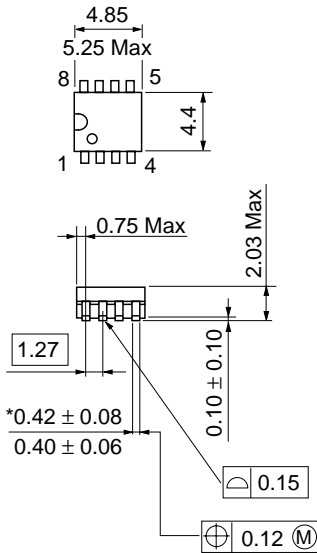
## Package Dimensions

Unit: mm



Hitachi Code	DP-8
JEDEC	Conforms
EIAJ	Conforms
Mass (reference value)	0.54 g

Unit: mm



Hitachi Code	FP-8D
JEDEC	—
EIAJ	Conforms
Mass (reference value)	0.10 g

\*Dimension including the plating thickness  
Base material dimension

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# HITACHI

## Hitachi, Ltd.

Semiconductor & Integrated Circuits.

Nippon Bldg., 2-6-2, Ohite-machi, Chiyoda-ku, Tokyo 100-0004, Japan

Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

URL      NorthAmerica      : <http://semiconductor.hitachi.com/>  
 Europe                    : <http://www.hitachi-eu.com/hel/ecg>  
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## For further information write to:

Hitachi Semiconductor  
 (America) Inc.  
 179 East Tasman Drive,  
 San Jose, CA 95134  
 Tel: <1> (408) 433-1990  
 Fax: <1> (408) 433-0223

Hitachi Europe GmbH  
 Electronic components Group  
 Dornacher Straße 3  
 D-85622 Feldkirchen, Munich  
 Germany  
 Tel: <49> (89) 9 9180-0  
 Fax: <49> (89) 9 29 30 00

Hitachi Europe Ltd.  
 Electronic Components Group.  
 Whitebrook Park  
 Lower Cookham Road  
 Maidenhead  
 Berkshire SL6 8YA, United Kingdom  
 Tel: <44> (1628) 585000  
 Fax: <44> (1628) 778322

Hitachi Asia Pte. Ltd.  
 16 Collyer Quay #20-00  
 Hitachi Tower  
 Singapore 049318  
 Tel: 535-2100  
 Fax: 535-1533

Hitachi Asia Ltd.  
 Taipei Branch Office  
 3F, Hung Kuo Building, No.167,  
 Tun-Hwa North Road, Taipei (105)  
 Tel: <886> (2) 2718-3666  
 Fax: <886> (2) 2718-8180

Hitachi Asia (Hong Kong) Ltd.  
 Group III (Electronic Components)  
 7/F., North Tower, World Finance Centre,  
 Harbour City, Canton Road, Tsim Sha Tsui,  
 Kowloon, Hong Kong  
 Tel: <852> (2) 735 9218  
 Fax: <852> (2) 730 0281  
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